

Vision 310 PECVD

INNOVATION • EXCELLENCE • PARTNERSHIP ENABLING SUSTAINABLE SUCCESS

Advanced-Vacuum.com

Vision 310 PECVD – Innovative Design and Construction

Vision systems provide a flexible, highly reliable, and economical platform for fundamental plasma deposition processing





Easy access for outstanding ease of service and maintenance

- Allows quick removal of chamber components for cleaning or swap
- Minimized maintenance intervals
 - Shorter clean cycles with small plasma volume
 - Low particulates
- Innovative showerhead design for highly uniform gas delivery
- Only un-doped depositions possible
- Stress control of Si₃N₄ achieved by using mixed-frequency deposition or low-damage He dilution
- N₂O/SF₆ etch back process (high rate when using low frequency)
- Showerhead-to-substrate distance is adjustable, accommodating non-standard substrates

Elegant design and construction has made the Vision highly valued by many prominent research institutions and Fortune 500 companies

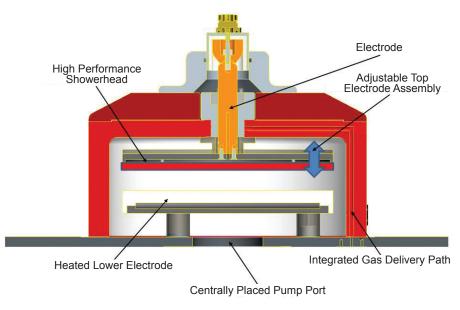
- Field proven with reliable proprietary technology
- ◆ Simple, robust, and intuitive operation and maintenance
- ◆ Compact footprint (<0.6m²) conserves valuable facility space
- ◆ Repeatable and uniform in-wafer and wafer-to-wafer performance
- ◆ Large (280mm) platen and easily accessible manual loading for standard and non-standard substrates

Vision PECVD configurations are fully characterized for a wide range of deposition processes:

- ◆ a-Si:H
- ♦ SiO₂
- Si₃N₄ (stress control)
- ◆ SiON
- SiC

Built for users with demanding and critical applications

- ◆ R&D Fundamental semiconductor and material science research for thin film deposition
- Prototyping and Low Volume Production economical solutions



Cross section of Vision 310 PECVD chamber

Productivity Enhancements

- Process Library: Vision systems come with a well-developed process library.
- Data Logging: Simplified data collection for sharing process monitoring and recipe information.
- Factory Communication: When enabled and combined with advanced self-diagnostic features, the system communicates status to the factory, assisting preventive maintenance scheduling and detecting abnormal issues.
- Best-of-breed (Tier 1) OEM components:
 Standard off-the-shelf for fast parts availability and efficient maintenance.

Proven open load system installed worldwide at leading universities and facilities

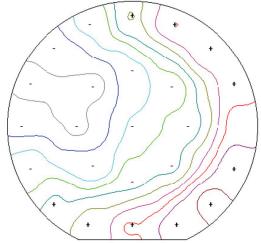
- User-friendly graphical control system
- Digital communication using DeviceNet
- Data logging and recipe management through open SQL Server environment
- ◆ Alarm history, on-the-fly recipe control
- ◆ Real-time process data display
- Easy and safe override maintenance screens
- Multiple user access levels



User-friendly interface

Patented endpoint system available for in-situ chamber clean (OES) using EndpointWorks®

Deposition uniformity

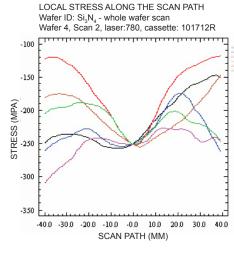


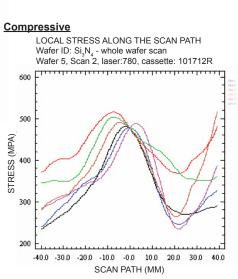
Nanospec / AFT - Contour Map

Program: SiO ₂ on Si 25pt 200mm - 3mm edge exclusion	
STATISTICS	
No of Data:	25
Min:	3733.8
Max:	3827.0
Range:	93.2
Mean:	3774.86
SD:	28.87
3SD:	86.62
% 3SD:	2.29%
%Range:	1.23%
%MinMax:	1.23%

Mixed-frequency stress control capability

Tensile





Vision 310 PECVD Specifications

12" Platen

930

Electrode Size	12" (305mm) diameter
Electrode Temperature	≤380°C
Electrode Material	Aluminum
Upper Electrode RF Power	Capacitive, 300W power supply, 13.56 MHz
Vacuum Pumping	250 m³/h Roots blower package
Base Pressure	<1.0 x 10 ⁻⁶ Torr
Pressure Control	Automatic, 0 – 1 Torr
Gas Lines	5 channels standard, (Digital MFCs)
Control System	PLC, DeviceNet
Software	Graphical control system with data logging
Power Requirements	32A @ 200/208 V, 60 Hz, 3 phase 25A @ 380/400 V, 50 Hz, 3 phase
Dimensions Height Depth Width	117.2 cm (214.7 cm with gas box mounted on system) 93.4 cm 73.0 cm
Certifications	CE, SEMI-2, S8
Options	Mixed-frequency stress control option for SiNx (500W 100-460 KHz) Endpoint: Optical Emission Spectroscopy (OES) Dry backing pump Additional gas lines (up to 10 total) Chamber wall heater Industrial communication SECS/GEM

